

AMENDMENTS TO THE SPECIFICATION

Please amend the first paragraph on page 1 as follows:

This is a divisional application of Application Serial No. 10/315,394 filed on December 10, 2002, now abandoned.

Please amend the second paragraph on page 1 as follows:

The present application is related to Application Serial No. 10/315,300 for "MOS Transistor and Method of Forming the Transistor with a Channel Region in a Layer of Composite Material" by Abdalla Aly Naem filed on an even date herewith. filed on December 10, 2002, now U.S. Patent No. 6,818,938, and Application Serial No. 10/869,158 filed on June 16, 2004.